



Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently Amended) A semiconductor device, comprising:  
a diode, including:  
an insulating substrate;  
a p-type silicon layer, ~~the p-type silicon layer~~ containing germanium, ~~and the p-type silicon layer~~ being disposed on the insulating substrate; and  
an n-type silicon layer joined to the p-type silicon layer ~~and the layer~~,  
the n-type silicon layer being disposed on the insulating substrate; and  
the p-type silicon layer being surrounded by the n-type silicon layer.
2. (Currently Amended) A semiconductor device, comprising:  
a diode, including:  
an insulating substrate;  
a p-type silicon layer, the p-type silicon layer containing germanium;  
an intrinsic silicon layer joined to the p-type silicon layer; and  
an n-type silicon layer joined to the intrinsic silicon layer,  
the p-type silicon layer, the intrinsic silicon layer and the n-type silicon layer  
being disposed on the insulating ~~substrate~~ substrate,  
the intrinsic silicon layer being surrounded by the n-type silicon layer, and  
the p-type silicon layer being surrounded by the intrinsic silicon layer.
3. (Canceled)
4. (Original) The semiconductor device according to claim 1, having a plurality of diodes, and further comprising:

a bridge-rectifier circuit comprising the diodes, and rectifying a predetermined alternating-current voltage to a direct-current voltage.

5. (Original) The semiconductor device according to claim 4, comprising:  
a coil antenna coupled to one side of the bridge-rectifier circuit; and  
a smoothing capacitor coupled to the other side of the bridge-rectifier circuit,  
the coil antenna generating an alternating-current voltage by electromagnetic induction;

the bridge-rectifier circuit rectifying the alternating-current voltage supplied thereto into a direct-current voltage; and

the smoothing capacitor smoothing the direct-current voltage supplied thereto into a constant voltage.

6-7. (Canceled)

8. (Original) The semiconductor device according to claim 2, having a plurality of diodes, and further comprising:

a bridge-rectifier circuit comprising the diodes, and rectifying a predetermined alternating-current voltage to a direct-current voltage.

9-11. (Canceled)